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MOSFET - Power, Single N-Channel, DFN5/DFNW5 40 V, 3.7 m Ω , 87 A

NVMFS5C456NL

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFS5C456NLWF Wettable Flank Option for Enhanced Optical Inspection
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage	Э		V_{GS}	±20	V
Continuous Drain		T _C = 25°C	I _D	87	Α
Current R _{θJC} (Notes 1, 3)	Steady	T _C = 100°C		61	
Power Dissipation	State	$T_C = 25^{\circ}C$	P_{D}	55	W
R _{θJC} (Note 1)		T _C = 100°C		27	
Continuous Drain		T _A = 25°C	I _D	22	Α
Current R _{θJA} (Notes 1, 2, 3)	Steady	T _A = 100°C		16	
Power Dissipation	State	T _A = 25°C	P_{D}	3.6	W
R _{θJA} (Notes 1 & 2)		T _A = 100°C		1.8	
Pulsed Drain Current	$T_A = 25^{\circ}C$, $t_p = 10 \mu s$		I _{DM}	520	Α
Operating Junction and Storage Temperature			T _J , T _{stg}	-55 to + 175	°C
Source Current (Body Diode)			I _S	61	Α
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 5 A)			E _{AS}	202	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C	

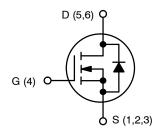
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	2.7	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	42	

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
- 3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX	
40 V	3.7 m Ω @ 10 V	87 A	
40 V	6.0 mΩ @ 4.5 V	87 A	



N-CHANNEL MOSFET

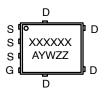




DFN5 (SO-8FL) CASE 488AA

DFNW5 (FULL-CUT SO8FL WF) CASE 507BE

MARKING DIAGRAM



XXXXXX = 5C456L

(NVMFS5C456NL) or

456LWF

(NVMFS5C456NLWF)

A = Assembly Location

Y = Year W = Work

W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

$\textbf{ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}\text{C unless otherwise specified})$

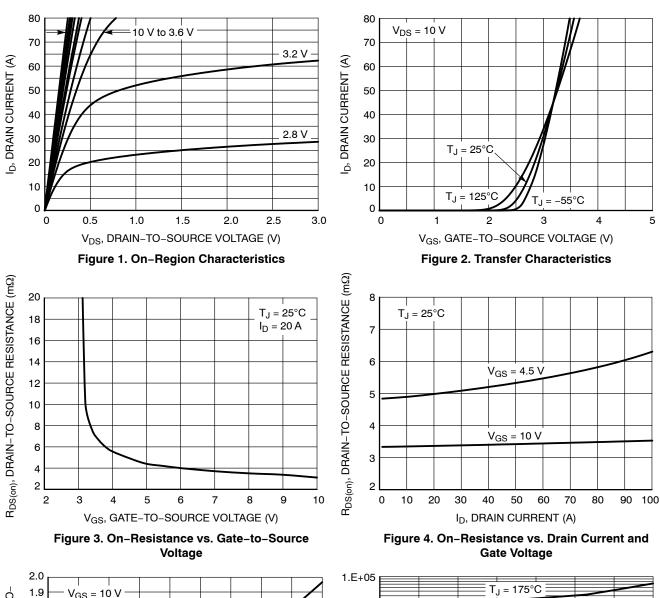
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS								
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40			V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /				22		mV/°C	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25 °C			10		
		V _{DS} = 40 V	T _J = 125°C			250	μΑ	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _G	_{áS} = 20 V			100	nA	
ON CHARACTERISTICS (Note 4)								
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 50 \mu A$		1.2		2.0	V	
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.1		mV/°C	
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V	I _D = 20 A		4.8	6.0		
		V _{GS} = 10 V	I _D = 20 A		3.1	3.7	mΩ	
Forward Transconductance	9 _{FS}	V _{DS} =15 V, I _E	_O = 40 A		80		S	
CHARGES, CAPACITANCES & GATE RE	SISTANCE				-			
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V			1600			
Output Capacitance	C _{OSS}				590		pF	
Reverse Transfer Capacitance	C _{RSS}				21			
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 20 V; I _D = 40 A			18		nC	
Total Gate Charge	Q _{G(TOT)}				8.2			
Threshold Gate Charge	Q _{G(TH)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 20 \text{ V}; I_D = 40 \text{ A}$			2		nC	
Gate-to-Source Charge	Q _{GS}				3.8			
Gate-to-Drain Charge	Q_{GD}				2.1			
Plateau Voltage	V_{GP}				3.2		V	
SWITCHING CHARACTERISTICS (Note 5	5)							
Turn-On Delay Time	t _{d(ON)}				9.3			
Rise Time	t _r	V _{GS} = 4.5 V, V	_{DS} = 20 V,		100		1	
Turn-Off Delay Time	t _{d(OFF)}	V_{GS} = 4.5 V, V_{DS} = 20 V, I_{D} = 40 A, R_{G} = 1 Ω			17		ns -	
Fall Time	t _f				4			
DRAIN-SOURCE DIODE CHARACTERIS	TICS							
Forward Diode Voltage	V _{SD}	V(3S - 0 V,	T _J = 25°C		0.86	1.2	.,,	
		I _S = 40 A	T _J = 125°C		0.75		V	
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V, } dI_{S}/dt = 100 \text{ A/}\mu\text{s,}$ $I_{S} = 40 \text{ A}$			29			
Charge Time	ta				14		ns	
Discharge Time	t _b				15]	
Reverse Recovery Charge	Q _{RR}				20		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: pulse width ≤ 300 µs, duty cycle ≤ 2%.

5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



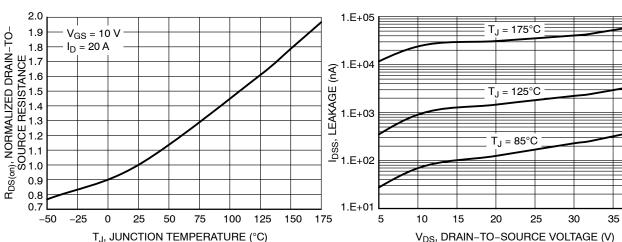


Figure 5. On–Resistance Variation with Temperature

Figure 6. Drain-to-Source Leakage Current vs. Voltage

40

TYPICAL CHARACTERISTICS

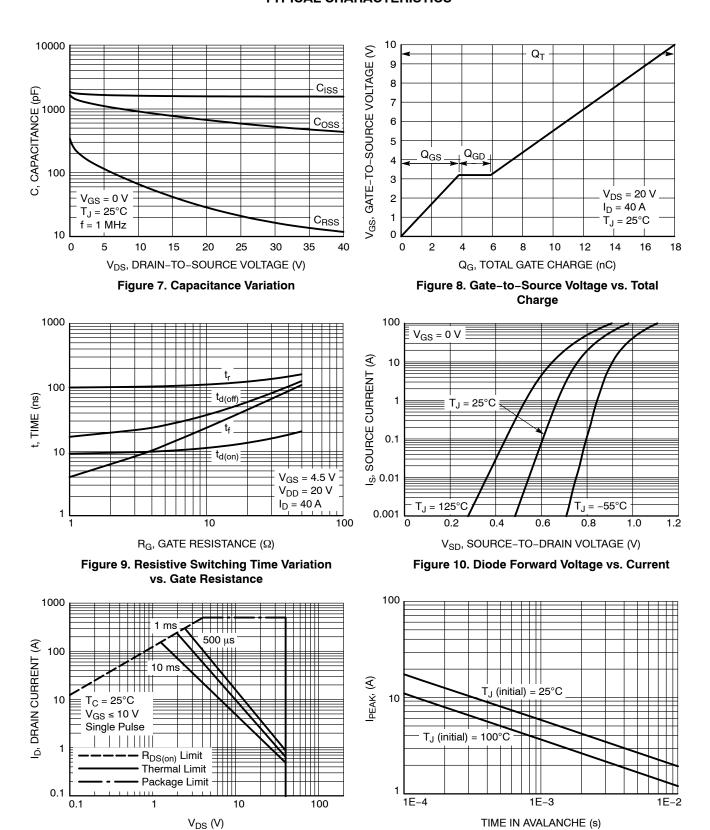


Figure 11. Safe Operating Area

Figure 12. $I_{\mbox{\scriptsize PEAK}}$ vs. Time in Avalanche

TYPICAL CHARACTERISTICS

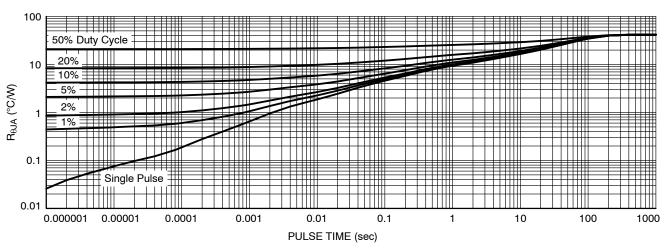


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS5C456NLET1G-YE	5C456L	DFN5 (Pb-Free)	1500 / Tape & Reel
NVMFS5C456NLT1G	5C456L	DFN5 (Pb-Free)	1500 / Tape & Reel
NVMFS5C456NLWFT1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel
NVMFS5C456NLT3G	5C456L	DFN5 (Pb-Free)	5000 / Tape & Reel
NVMFS5C456NLWFT3G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	5000 / Tape & Reel
NVMFS5C456NLAFT1G	5C456L	DFN5 (Pb-Free)	1500 / Tape & Reel
NVMFS5C456NLAFT1G-YE	5C456L	DFN5 (Pb-Free)	1500 / Tape & Reel
NVMFS5C456NLWFAFT1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel
NVMFS5C456NLWFET1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel
NVMFS5C456NLWFET3G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SIDE VIEW





DFN5 5x6, 1.27P (SO-8FL) CASE 488AA ISSUE N

DATE 25 JUN 2018

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION D1 AND E1 DO NOT INCLUDE
- MOLD FLASH PROTRUSIONS OR GATE BURRS

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.90	1.00	1.10	
A1	0.00	-	0.05	
b	0.33	0.41	0.51	
С	0.23	0.28	0.33	
D	5.00	5.15	5.30	
D1	4.70	4.90	5.10	
D2	3.80	4.00	4.20	
E	6.00	6.15	6.30	
E1	5.70	5.90	6.10	
E2	3.45	3.65	3.85	
е		1.27 BSC		
G	0.51	0.575	0.71	
K	1.20	1.35	1.50	
L	0.51	0.575	0.71	
L1	0.125 REF			
М	3.00	3.40	3.80	
θ	0 °		12 °	

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code

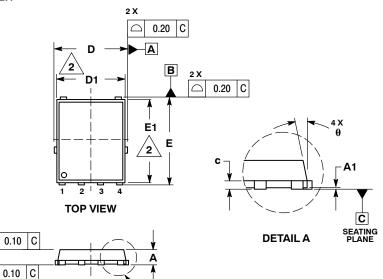
= Assembly Location Α

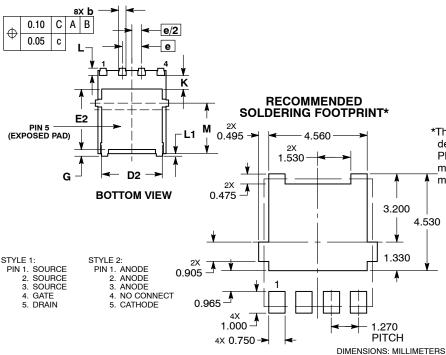
= Lot Traceability

Υ = Year W = Work Week

ZZ

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.





DETAIL A

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PIN 1

IDENTIFIER

// 0.10 C

□ 0.10 C

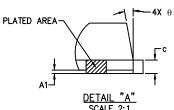
DFNW5 4.90x5.90x1.00, 1.27P

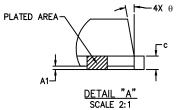
CASE 507BE **ISSUE A**

DATE 15 JUL 2024

NOTES:

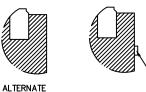
- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M-2018.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH. PROTRUSIONS, OR GATE BURRS.
- THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

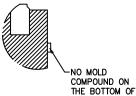






✠





TIE BAR.

MILLIMETERS DIM MIN NOM MAX Α 0.90 1.00 1.10 Α1 0.00 0.25 0.05 0.41 0.51 ь 0.33 0.33 0.23 С 0.28 D 5.00 5.15 5.30 D1 4.70 4.90 5.10 D2 3.80 4.00 4.20 Ε 6.00 6.15 6.30 E1 5.70 5.90 6.10 E2 3.45 3.65 3.85 E3 3.00 3.40 3.80 е 1.27 BSC 1.50 1.20 1.35 0.51 0.57 0.71 L2 0.15 REF 12° θ 0. 6*

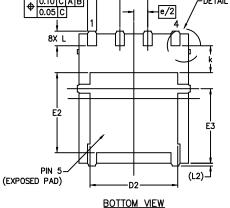
0.10 C A B DETAIL B CONSTRUCTION 0.05 C

TOP VIEW

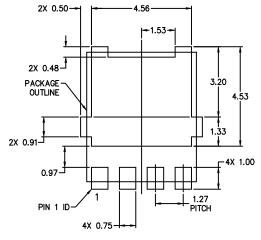
DETAIL A

SIDE VIEW

SEATING



DETAIL "B" SCALE 2:1



RECOMMENDED MOUNTING FOOTPRINT* *FOR ADDITIONAL INFORMATION ON OUR PD-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.

GENERIC MARKING DIAGRAM*



= Assembly Location Α Υ = Year

W = Work Week 77 = Lot Traceability

XXXXXX = Specific Device Code *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION: DFNW5 4.90x5.90x1.00, 1.27P **PAGE 1 OF 1**

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